INTEGRATED CIRCUITS

DATA SHEET

74ALVC74

Dual D-type flip-flop with set and reset; positive-edge trigger

Product specification Supersedes data of 2002 Nov 15 2003 Jan 24

Philips
Semiconductors





Dual D-type flip-flop with set and reset; positive-edge trigger

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FEATURES

- Wide supply voltage range from 1.65 to 3.6 V
- Complies with JEDEC standard: JESD8-7 (1.65 to 1.95 V)
 JESD8-5 (2.3 to 2.7 V)
 JESD8B/JESD36 (2.7 to 3.6 V)
- 3.6 V tolerant inputs/outputs
- CMOS low power consumption
- Direct interface with TTL levels (2.7 to 3.6 V)
- Power-down mode
- · Latch-up performance exceeds 250 mA
- ESD protection: HBM EIA/JESD22-A114-A exceeds 2000 V MM EIA/JESD22-A115-A exceeds 200 V.

DESCRIPTION

The 74ALVC74 is a dual positive-edge triggered, D-type flip-flop with individual data (D), clock (CP), set (\overline{S}_D) and reset (\overline{R}_D) inputs and complementary Q and \overline{Q} outputs.

The set and reset are asynchronous active LOW inputs and operate independently of the clock input. Information on the data input is transferred to the Q output on the LOW-to-HIGH transition of the clock pulse. The D inputs must be stable one set-up time prior to the LOW-to-HIGH clock transition for predictable operation.

Schmitt-trigger action in the clock input makes the circuit highly tolerant to slower clock rise and fall times.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	propagation delay nCP to nQ, nQ	$V_{CC} = 1.8 \text{ V}; C_L = 30 \text{ pF}; R_L = 1 \text{ k}\Omega$	3.7	ns
		$V_{CC} = 2.5 \text{ V}; C_L = 30 \text{ pF}; R_L = 500 \Omega$	2.6	ns
		$V_{CC} = 2.7 \text{ V; } C_L = 50 \text{ pF; } R_L = 500 \Omega$	2.8	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 50 \text{ pF}; R_L = 500 \Omega$	2.7	ns
t _{PHL} /t _{PLH}	propagation delay $n\overline{S}_D$, $n\overline{R}_D$ to nQ , $n\overline{Q}$	$V_{CC} = 1.8 \text{ V}; C_L = 30 \text{ pF}; R_L = 1 \text{ k}\Omega$	3.5	ns
		$V_{CC} = 2.5 \text{ V}; C_L = 30 \text{ pF}; R_L = 500 \Omega$	2.5	ns
		$V_{CC} = 2.7 \text{ V}; C_L = 50 \text{ pF}; R_L = 500 \Omega$	3.1	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 50 \text{ pF}; R_L = 500 \Omega$	2.3	ns
f _{max}	maximum clock frequency		425	MHz
Cı	input capacitance		3.5	pF
C _{PD}	power dissipation capacitance per buffer	V _{CC} = 3.3 V; notes 1 and 2	35	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total switching outputs;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

2. The condition is $V_I = GND$ to V_{CC} .

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ORDERING INFORMATION

TYPE NUMBER	PACKAGE				
I TPE NUMBER	PINS	PACKAGE	MATERIAL	CODE	
74ALVC74D	14	SO14	plastic	SOT108-1	
74ALVC74PW	14	TSSOP14	plastic	SOT402-1	

FUNCTION TABLES

Table 1 See note 1

INPUT				OUTPUT		
n S _D	$n\overline{R}_D$	nCP	nD	nQ	nQ	
L	Н	Х	X	Н	L	
Н	L	Х	Х	L	Н	
L	L	X	X	Н	Н	

Table 2 See note 1

INPUT				OUTPUT		
n S _D	$n\overline{R}_D$	nCP	nD	nQ_{n+1} $n\overline{Q}_{n+1}$		
Н	Н	1	L	L	Н	
Н	Н	1	Н	Н	L	

Note

1. H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

↑ = LOW-to-HIGH CP transition;

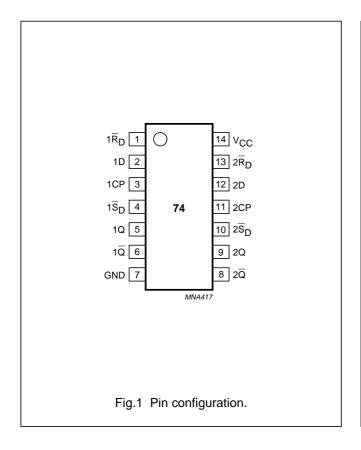
 Q_{n+1} = state after the next LOW-to-HIGH transition of CP.

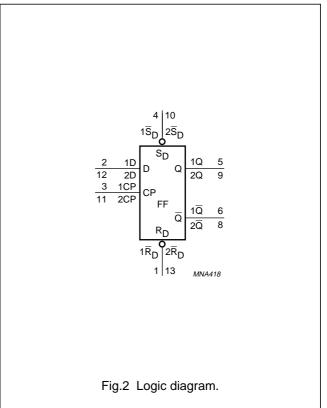
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PINNING

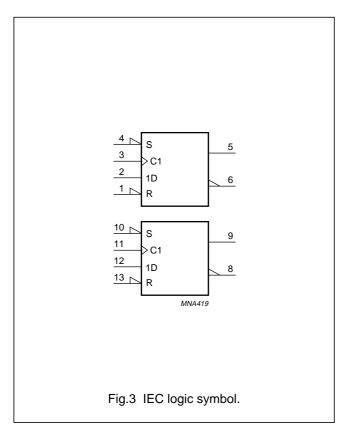
PIN	SYMBOL	DESCRIPTION
1	1RD	asynchronous reset-direct input (active LOW)
2	1D	data input
3	1CP	clock input (LOW-to-HIGH, edge-triggered)
4	1SD	asynchronous set-direct input (active LOW)
5	1Q	true flip-flop output
6	1Q	complement flip-flop output
7	GND	ground (0 V)
8	2Q	complement flip-flop output
9	2Q	true flip-flop output
10	2SD	asynchronous set-direct input (active LOW)
11	2CP	clock input (LOW-to-HIGH, edge-triggered)
12	2D	data input
13	$2\overline{R}_D$	asynchronous reset-direct input (active LOW)
14	V _{CC}	supply voltage

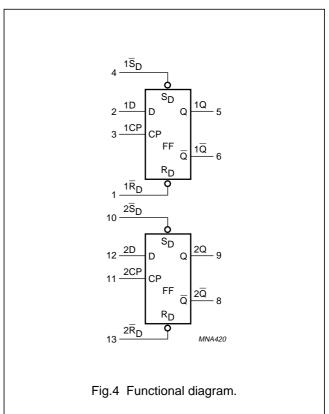


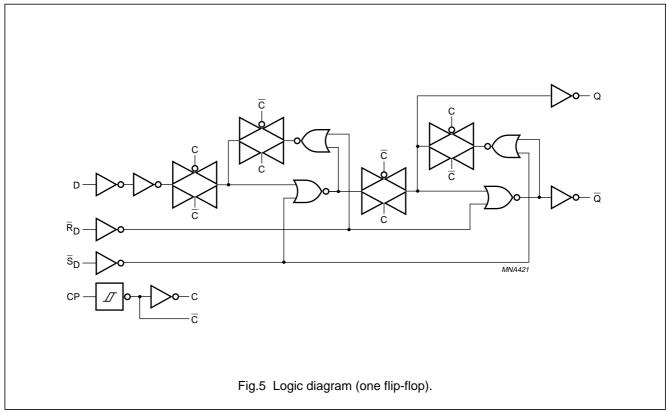


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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	supply voltage		1.65	3.6	V
V _I	input voltage		0	3.6	V
Vo	output voltage	V _{CC} = 1.65 to 3.6 V	0	V _{CC}	V
		V _{CC} = 0 V; Power-down mode	0	3.6	V
T _{amb}	operating ambient temperature		-40	+85	°C
t _r , t _f	input rise and fall times	V _{CC} = 1.65 to 2.7 V	0	20	ns/V
		V _{CC} = 2.7 to 3.6 V	0	10	ns/V

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input diode current	V _I < 0	_	-50	mA
V _I	input voltage		-0.5	+4.6	V
I _{OK}	output diode current	$V_O > V_{CC}$ or $V_O < 0$	_	±50	mA
Vo	output voltage	notes 1 and 2	-0.5	V _{CC} + 0.5	V
		Power-down mode; note 2	-0.5	+4.6	V
Io	output source or sink current	$V_O = 0$ to V_{CC}	_	±50	mA
I _{CC} , I _{GND}	V _{CC} or GND current		_	±100	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	power dissipation per package				
	SO package	above 70 °C derate linearly with 8 mW/K	_	500	mW
	TSSOP package	above 60 °C derate linearly with 5.5 mW/K	_	500	mW

Notes

- 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- 2. When $V_{CC} = 0 \text{ V}$ (Power-down mode), the output voltage can be 3.6 V in normal operation.

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DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

CVMPO	DADAMETER	TEST CONDITIONS		NAIN!	T)(D(1)	NA A V	LINIT
SYMBOL	PARAMETER	OTHER	V _{CC} (V)	MIN.	TYP. ⁽¹⁾	MAX.	UNIT
T _{amb} = -40	0 to +85 °C		•				
V _{IH}	HIGH-level input		1.65 to 1.95	0.65 × V _{CC}	_	_	V
	voltage		2.3 to 2.7	1.7	_	_	V
			2.7 to 3.6	2	_	_	V
V _{IL}	LOW-level input		1.65 to 1.95	-	_	$0.35 \times V_{CC}$	V
	voltage		2.3 to 2.7	_	_	0.7	V
			2.7 to 3.6	_	_	0.8	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}					
	voltage	I _O = 100 μA	1.65 to 3.6	_	_	0.2	V
		$I_O = 6 \text{ mA}$	1.65	_	0.11	0.3	V
		I _O = 12 mA	2.3	_	0.17	0.4	V
		I _O = 18 mA	2.3	_	0.25	0.6	V
		I _O = 12 mA	2.7	_	0.16	0.4	V
		I _O = 18 mA	3.0	_	0.23	0.4	V
		I _O = 24 mA	3.0	_	0.30	0.55	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}					
	voltage	$I_{O} = -100 \mu A$	1.65 to 3.6	V _{CC} – 0.2	_	_	V
		$I_O = -6 \text{ mA}$	1.65	1.25	1.51	_	V
		$I_{O} = -12 \text{ mA}$	2.3	1.8	2.10	_	V
		$I_{O} = -18 \text{ mA}$	2.3	1.7	2.01	_	V
		$I_{O} = -12 \text{ mA}$	2.7	2.2	2.53	_	V
		$I_{O} = -18 \text{ mA}$	3.0	2.4	2.76	_	V
		$I_{O} = -24 \text{ mA}$	3.0	2.2	2.68	_	V
lu	input leakage current	V _I = 3.6 V or GND	3.6	_	±0.1	±5	μΑ
l _{off}	power OFF leakage current	V_1 or $V_0 = 3.6 \text{ V}$	0.0	-	±0.1	±10	μА
I _{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$	3.6	-	0.2	10	μА
Δl _{CC}	additional quiescent supply current per input pin	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0$	3.0 to 3.6	-	5	750	μА

Note

1. All typical values are measured at T_{amb} = 25 °C.

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AC CHARACTERISTICS

CVMDOL	DADAMETED	TEST CON	DITIONS	NAIN!	TVD (1)	MAY	UNIT
SYMBOL	PARAMETER	OTHER	V _{CC} (V)	MIN.	TYP. ⁽¹⁾	MAX.	
T _{amb} = -40) to +85 °C		'				
t _{PHL} /t _{PLH}	propagation delay	see Figs 5 and 7	1.65 to 1.95	1.0	3.7	6.2	ns
	nCP to nQ, $n\overline{Q}$		2.3 to 2.7	1.0	2.6	4.2	ns
			2.7	1.0	2.8	4.2	ns
			3.0 to 3.6	1.0	2.7	3.8	ns
t _{PHL} /t _{PLH}	propagation delay	see Figs 6 and 7	1.65 to 1.95	1.0	3.4	5.4	ns
	$n\overline{S}_D$ to nQ , $n\overline{Q}$		2.3 to 2.7	1.0	2.4	3.8	ns
			2.7	1.0	3.2	4.2	ns
			3.0 to 3.6	1.0	2.3	3.5	ns
t _{PHL} /t _{PLH}	propagation delay	see Figs 6 and 7	1.65 to 1.95	1.0	3.5	5.4	ns
	$n\overline{R}_D$ to nQ , $n\overline{Q}$		2.3 to 2.7	1.0	2.5	3.8	ns
			2.7	1.0	3.1	4.3	ns
			3.0 to 3.6	1.0	2.3	3.5	ns
t _W	clock pulse width	see Figs 5 and 7	1.65 to 1.95	2.5	0.9	_	ns
	HIGH or LOW		2.3 to 2.7	2.5	0.6	_	ns
			2.7	2.5	1.3	_	ns
			3.0 to 3.6	2.5	1.3	_	ns
t _W	set or reset pulse width LOW	see Figs 6 and 7	1.65 to 1.95	2.5	0.9	_	ns
			2.3 to 2.7	2.5	0.9	_	ns
			2.7	2.5	1.0	_	ns
			3.0 to 3.6	2.5	0.7	_	ns
t _{rem}	removal time set or reset	see Figs 6 and 7	1.65 to 1.95	0.7	-0.2	_	ns
			2.3 to 2.7	0.7	-0.1	_	ns
			2.7	0.7	-0.1	_	ns
			3.0 to 3.6	0.7	-0.1	_	ns
t _{su}	set-up time nD to nCP	see Figs 5 and 7	1.65 to 1.95	1.2	0.6	_	ns
			2.3 to 2.7	1.2	0.8	_	ns
			2.7	0.9	0.5	_	ns
			3.0 to 3.6	0.8	0.4	_	ns
t _h	hold time nD to nCP	see Figs 5 and 7	1.65 to 1.95	0.6	-0.4	_	ns
			2.3 to 2.7	0.6	-0.3	_	ns
			2.7	0.7	-0.4	_	ns
			3.0 to 3.6	0.8	-0.1	_	ns

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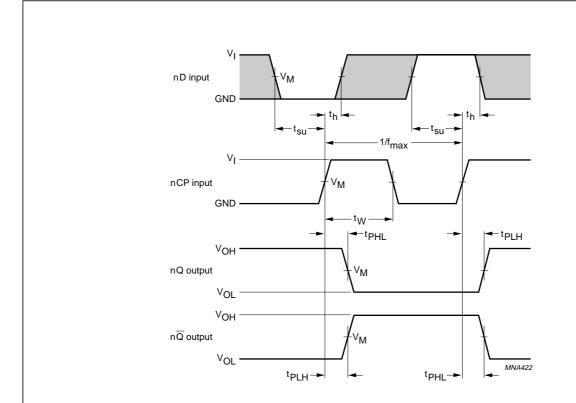
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SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP. ⁽¹⁾	MAX.	UNIT
STWIBOL	PARAIVIETER	OTHER	V _{CC} (V)	iviin.	I I P.(\')	WAA.	UNIT
f _{max}	maximum clock pulse	see Figs 5 and 7	1.65 to 1.95	150	275	_	MHz
	frequency	су	2.3 to 2.7	200	325	_	MHz
			2.7	250	375	_	MHz
			3.0 to 3.6	300	425	1	MHz

Note

1. All typical values are measured at T_{amb} = 25 °C.

AC WAVEFORMS

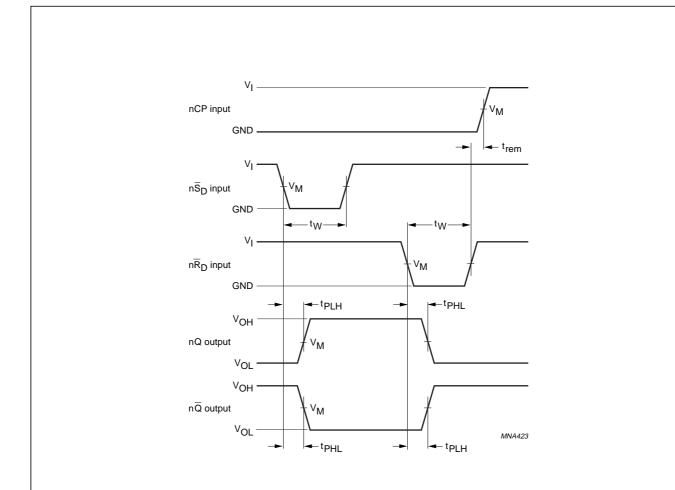


V	V	INPUT			
V _{CC}	V _M	VI	$t_r = t_f$		
1.65 to 1.95 V	$0.5 \times V_{CC}$	V _{CC}	≤ 2.0 ns		
2.3 to 2.7 V	$0.5 \times V_{CC}$	V _{CC}	≤ 2.0 ns		
2.7 V	1.5 V	2.7 V	≤ 2.5 ns		
3.0 to 3.6 V	1.5 V	2.7 V	≤ 2.5 ns		

Fig.5 The clock (nCP) to output (nQ, $n\overline{Q}$) propagation delays, the clock pulse width, the nD to nCP set-up, the nCP to nD hold times, the output transition times and the maximum clock pulse frequency.

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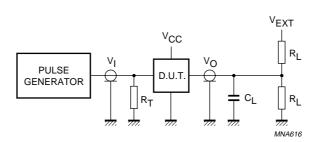


V	V	INF	PUT
V _{CC}	V _M	VI	$t_r = t_f$
1.65 to 1.95 V	$0.5 \times V_{CC}$	V _{CC}	≤ 2.0 ns
2.3 to 2.7 V	$0.5 \times V_{CC}$	V _{CC}	≤ 2.0 ns
2.7 V	1.5 V	2.7 V	≤ 2.5 ns
3.0 to 3.6 V	1.5 V	2.7 V	≤ 2.5 ns

Fig.6 The set $(n\overline{S}_D)$ and reset $(n\overline{R}_D)$ input to output $(nQ, n\overline{Q})$ propagation delays, the set and reset pulse widths and the $n\overline{R}_D$ to nCP removal time.

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V _{CC}	V _I C _L		R _L	V _{EXT}			
▼CC	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	CL	I KL	t _{PLH} /t _{PHL}	t _{PZH} /t _{PHZ}	t _{PZL} /t _{PLZ}	
1.65 to 1.95 V	V _{CC}	30 pF	1 kΩ	open	GND	$2 \times V_{CC}$	
2.3 to 2.7 V	V _{CC}	30 pF	500 Ω	open	GND	$2 \times V_{CC}$	
2.7 V	2.7 V	50 pF	500 Ω	open	GND	6 V	
3.0 to 3.6 V	2.7 V	50 pF	500 Ω	open	GND	6 V	

R_L = Load resistor.

 $\ensuremath{C_L}$ = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

Fig.7 Load circuitry for switching times.

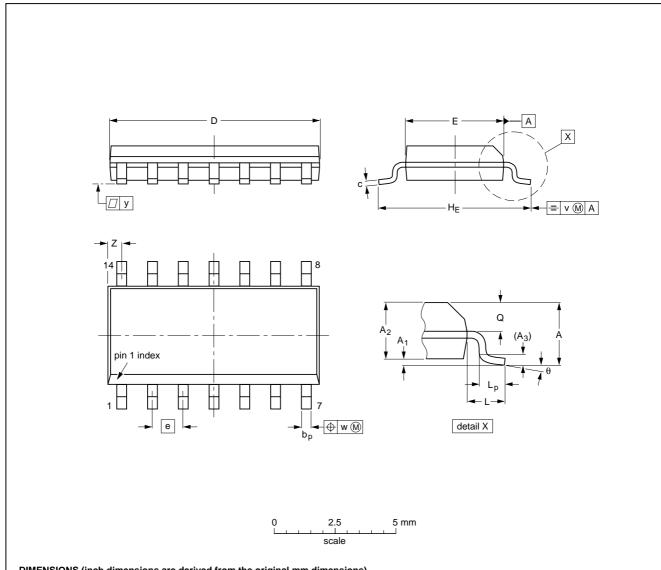
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PACKAGE OUTLINES

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Ø	v	w	у	z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.35 0.34	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT108-1	076E06	MS-012			97-05-22 99-12-27	

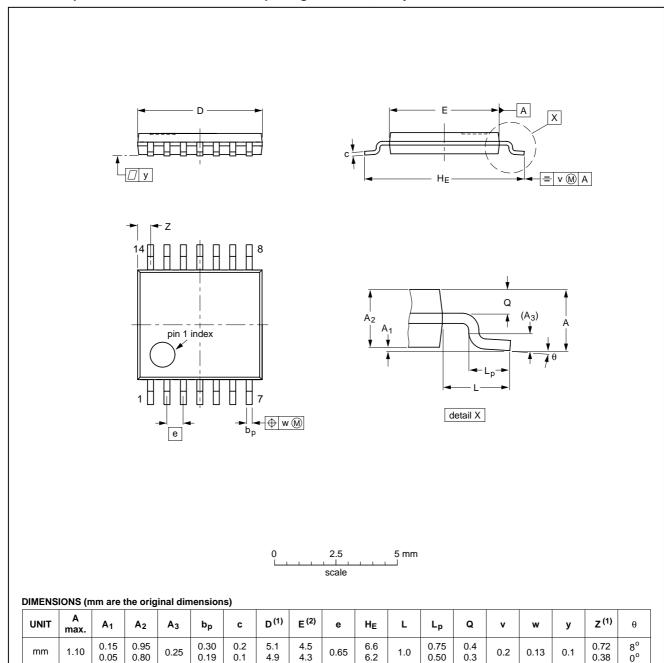
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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



mm

1.10

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

0.25

2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT402-1		MO-153				-95-04-04 99-12-27	

0.65

4.9

0.2

0.13

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SOLDERING

Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "Data Handbook IC26; Integrated Circuit Packages" (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferable be kept below 220 °C for thick/large packages, and below 235 °C for small/thin packages.

Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

 For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to $300\ ^{\circ}$ C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 $^{\circ}$ C.

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Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE ⁽¹⁾	SOLDERING METHOD			
PACKAGE	WAVE	REFLOW ⁽²⁾		
BGA, LBGA, LFBGA, SQFP, TFBGA, VFBGA	not suitable	suitable		
DHVQFN, HBCC, HBGA, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, HVQFN, HVSON, SMS	not suitable ⁽³⁾	suitable		
PLCC ⁽⁴⁾ , SO, SOJ	suitable	suitable		
LQFP, QFP, TQFP	not recommended ⁽⁴⁾⁽⁵⁾	suitable		
SSOP, TSSOP, VSO	not recommended ⁽⁶⁾	suitable		

Notes

- 1. For more detailed information on the BGA packages refer to the "(LF)BGA Application Note" (AN01026); order a copy from your Philips Semiconductors sales office.
- 2. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 3. These packages are not suitable for wave soldering. On versions with the heatsink on the bottom side, the solder cannot penetrate between the printed-circuit board and the heatsink. On versions with the heatsink on the top side, the solder might be deposited on the heatsink surface.
- 4. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 5. Wave soldering is suitable for LQFP, TQFP and QFP packages with a pitch (e) larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 6. Wave soldering is suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
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Notes

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